NSN 5961-01-568-3199

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Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-568-3199 **Inclosure Material:** Plastic **Overall Length:** Between 0.110 inches and 0.120 inches **Overall Height:** Between 0.035 inches and 0.044 inches **Overall Width:** Between 0.047 inches and 0.055 inches **Internal Configuration:** Junction contact-double emitter Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-236 **Internal Junction Configuration:** Npn **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 350.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Lead-free **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No